ELSEVIER

Surface Science 348 (1996) 393–395

surface science

Author index

Arce, H., W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379
Arnault, J.C., J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185

Baberschke, K., see Ritter 348 (1996) 243
Bailes III, A.A., see Boshart 348 (1996) L75
Barrera, A., see Rar 348 (1996) 77
Barteau, M.A., see Idriss 348 (1996) 39
Barteau, M.A., see Shekhar 348 (1996) 55
Barth, J.V., R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280
Behm, R.J., see Barth 348 (1996) 280
Boshart, M.A., A.A. Bailes III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75
Bowker, M., see Li 348 (1996) 67
Bradshaw, A.M., see Schaff 348 (1996) 89
Briggs, G.A.D., see Mayne 348 (1996) 209
Bronikowski, M.J. and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311
Bubendorff, J.L., see Arnault 348 (1996) 185
Bucher, J.P., see Arnault 348 (1996) 185

Campbell, C.T., see Gamble 348 (1996) 1
Cerdá, J., S. Gallego and P.L. de Andres, Fast first-order perturbation approach to the surface structural problem using low energy electron diffraction 348 (1996) 197
Chambers, S.A., see Gao 348 (1996) 17
Chiang, T.-C., see Roesler 348 (1996) 161
Comsa, G., see Wulfhekel 348 (1996) 227

Daolio, S., see Kristóf 348 (1996) 287
Davis, R., see Schaff 348 (1996) 89
De Andres, P.L., see Cerdá 348 (1996) 197
Doraiswamy, N. and L.D. Marks, Electron beam induced small particle transformations: temperature 348 (1996) L67

Ertl, G., see Barth 348 (1996) 280

Facchin, B., see Kristóf 348 (1996) 287
Farle, M., see Ritter 348 (1996) 243
Fernandez, V., see Schaff 348 (1996) 89
Finnis, M.W., see Tan 348 (1996) 49
Frederick, B.G., M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71
Fritzsche, V., see Schaff 348 (1996) 89

Gallego, S., see Cerdá 348 (1996) 197
Gamble, L., L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1
Gao, Y., Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped TiO_2(110) surfaces by molecular beam epitaxy 348 (1996) 17
Ge, Q., see Nerlov 348 (1996) 28
Glass, J.A., Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325
Goering, E., see Goschke 348 (1996) 305
Goringe, C.M., see Mayne 348 (1996) 209
Goschke, R.A., K. Vey, M. Meier, U. Walter, E. Goering, M. Klemm and S. Horn, Tip induced changes of atomic scale images of the vanadiumpentoxide surface 348 (1996) 305
Gutiérrez, J.J., see Arce 348 (1996) 379

Hamers, R.J., see Bronikowski 348 (1996) 311
Hara, S., see Ikemiya 348 (1996) 253
Hasegawa, Y., see Yamamoto 348 (1996) 133
Hirose, K., see Kobayashi 348 (1996) 299
Hofmann, Ph., see Schaff 348 (1996) 89
Horio, Y. and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344
Horn, S., see Goschke 348 (1996) 305
Horsfield, A.P., see Tan 348 (1996) 49
Huang, H.H., C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

Ichimiya, A., see Horio 348 (1996) 344
Idriss, H., V.S. Lusvardi and M.A. Barteau, Two routes to formaldehyde from formic acid on TiO_2(001) surfaces 348 (1996) 39
Ikemiya, N., K. Yamada and S. Hara, Initial stage of the electrodeposition of Ag on Au(100) observed by in-situ atomic force microscopy 348 (1996) 253

Jenks, C.J., S. Rishi and P.A. Thiel, Effectiveness of a fluorinated nickel surface in catalyzing the decomposition of a perfluoropolyether analog 348 (1996) 175

Jones, R.G., see Walter 348 (1996) 115
Jorritsma, L.C., see Wulfhekel 348 (1996) 227
Jung, L.S., see Gamble 348 (1996) 1

Khater, A., see Pennec 348 (1996) L82
Klemm, M., see Goschke 348 (1996) 305
Kliewer, J., see Wulfhekel 348 (1996) 227
Knutsen, K. and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143
Kobayashi, N., K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299
Kokko, K., P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168
Komeda, T., Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153
Kristóf, J., S. Daolio, C. Piccirillo, B. Facchin and J. Mink, Investigation on the formation of RuO_2 film electrode by secondary ion mass spectrometry 348 (1996) 287

Laihia, R., see Kokko 348 (1996) 168
Lee, M.B., see Frederick 348 (1996) L71
Li, Y. and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67
Liang, Y., see Gao 348 (1996) 17
Lipkin, N.N., see Wulfhekel 348 (1996) 227
Lusvardi, V.S., see Idriss 348 (1996) 39

Manolopoulos, D.E., see Walter 348 (1996) 115
Mansikka, K., see Kokko 348 (1996) 168
Marks, L.D., see Doraiswamy 348 (1996) L67
Matsushima, T., see Rar 348 (1996) 77
Mayne, A.J., C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209
Meier, M., see Goschke 348 (1996) 305
Miller, T., see Roesler 348 (1996) 161
Mink, J., see Kristóf 348 (1996) 287
Minoda, H., see Suzuki 348 (1996) 335
Mochán, W.L., see Arce 348 (1996) 379
Møller, P.J., see Nerlov 348 (1996) 28
Morita, Y., see Komeda 348 (1996) 153

Nagao, T., see Yamamoto 348 (1996) 133
Nerlov, J., Q. Ge and P.J. Møller, Resonant photoemission from TiO_2(110) surfaces: implications on surface bonding and hybridization 348 (1996) 28
Nishizawa, J., Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105

Oechsner, H., see Šroubek 348 (1996) 100
Ohno, Y., see Rar 348 (1996) 77
Orlando, T.M., see Knutsen 348 (1996) 143
Oshima, C., see Yamamoto 348 (1996) 133
Otani, S., see Yamamoto 348 (1996) 133
Oyama, Y., see Nishizawa 348 (1996) 105

Pennec, Y. and A. Khater, A method for characterizing the localized dynamics of boundary defects in crystalline systems 348 (1996) L82
Piccirillo, C., see Kristóf 348 (1996) 287
Pimpinelli, A., see Arnault 348 (1996) 185
Plotka, P., see Nishizawa 348 (1996) 105
Poelsema, B., see Wulfhekel 348 (1996) 227

Rar, A., H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77
Richardson, N.V., see Frederick 348 (1996) L71
Rishi, S., see Jenks 348 (1996) 175
Ritter, M., M. Stindtmann, M. Farle and K. Baberschke, Nanostructuring of the Cu(001) surface by ion bombardment: a STM study 348 (1996) 243
Roesler, J.M., T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161
Rokuta, E., see Yamamoto 348 (1996) 133
Rosenfeld, G., see Wulfhekel 348 (1996) 227

Sakai, H., How does a slab-shaped solid melt? 348 (1996) 387
Sakuraba, H., see Nishizawa 348 (1996) 105
Salo, P.T., see Kokko 348 (1996) 168
Schaff, O., V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89
Schindler, K.-M., see Schaff 348 (1996) 89
Schmidt, U., S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261
Schuster, R., see Barth 348 (1996) 280
Seet, C.S., see Huang 348 (1996) 192
Seiberling, L.E., see Boshart 348 (1996) L75
Shekhar, R. and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55
Smith, C.W., see Mayne 348 (1996) 209
Sreekanth, C.S., see Huang 348 (1996) 192
Šroubek, Z. and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100
Staikov, G., see Schmidt 348 (1996) 261
Steinrück, H.-P., see Stichler 348 (1996) 370
Stichler, M., P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370
Stindtmann, M., see Ritter 348 (1996) 243
Sugimura, H., see Rar 348 (1996) 77
Sugino, O., see Yamauchi 348 (1996) L70
Sutton, A.P., see Tan 348 (1996) 49
Suzuki, T., H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Tan, K.E., M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49
Tanishiro, Y., see Suzuki 348 (1996) 335

Theobald, A., see Schaff 348 (1996) 89
Thiel, P.A., see Jenks 348 (1996) 175
Tokumoto, H., see Komeda 348 (1996) 153
Trenary, M., see Yamamoto 348 (1996) 133
Tsukada, M., see Yamauchi 348 (1996) L70
Tsukada, M., see Kobayashi 348 (1996) 299

Vey, K., see Goschke 348 (1996) 305
Vinzelberg, S., see Schmidt 348 (1996) 261

Walter, U., see Goschke 348 (1996) 305
Walter, W.K., D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
Watanabe, S., see Yamauchi 348 (1996) L70
Weare, C.B. and J.A. Yarmoff, Resonant neutralization of $^{7}Li^{+}$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359
Weinelt, M., see Stichler 348 (1996) 370
Woodruff, D.P., see Schaff 348 (1996) 89
Wovchko, E.A., see Glass 348 (1996) 325
Wulfhekel, W., N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

Xu, G.Q., see Huang 348 (1996) 192

Yagi, K., see Suzuki 348 (1996) 335
Yamada, K., see Ikemiya 348 (1996) 253
Yamamoto, N., E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the PrB_6(100) and LaB_6(100) surfaces 348 (1996) 133
Yamauchi, J., M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70
Yarmoff, J.A., see Weare 348 (1996) 359
Yates, J.T., see Glass 348 (1996) 325

Zebisch, P., see Stichler 348 (1996) 370

ELSEVIER

Surface Science 348 (1996) 396–401

surface science

Subject index

THEORETICAL METHODS, MODELS AND TECHNIQUES

Atom–solid interactions, scattering, diffraction

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Computer simulations

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49

K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168

M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75

N. Kobayashi, K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299

Density functional calculations

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70

K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168

N. Kobayashi, K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299

Electron–solid interactions, scattering, diffraction

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161

J. Cerdá, S. Gallego and P.L. de Andres, Fast first-order perturbation approach to the surface structural problem using low energy electron diffraction 348 (1996) 197

Y. Horio and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344

Equilibrium thermodynamics and statistical mechanics

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

H. Sakai, How does a slab-shaped solid melt? 348 (1996) 387

Ion–solid interactions, scattering, channeling

M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75

Models of non-equilibrium phenomena

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Models of surface kinetics

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

Molecular dynamics

K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168

Semi-empirical models and model calculations

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49

EXPERIMENTAL SAMPLE PREPARATION AND CHARACTERIZATION METHODS

Atom–solid scattering and diffraction – elastic

W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

Atomic force microscopy

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped TiO_2(110) surfaces by molecular beam epitaxy 348 (1996) 17

J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185

N. Ikemiya, K. Yamada and S. Hara, Initial stage of the electrodeposition of Ag on Au(100) observed by in-situ atomic force microscopy 348 (1996) 253

Auger electron spectroscopy

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Chemical vapor deposition

M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Desorption induced by electronic transitions (DIET)

Electron stimulated desorption (ESD)

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

Electrical transport measurements

J. Nishizawa, Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105

Electrochemical methods

U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261

Electron energy loss spectroscopy

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the $PrB_6(100)$ and $LaB_6(100)$ surfaces 348 (1996) 133

B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71

Electron microscopy

N. Doraiswamy and L.D. Marks, Electron beam induced small particle transformations: temperature 348 (1996) L67

Reflection electron microscopy (REM)

T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Electron–solid diffraction

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped $TiO_2(110)$ surfaces by molecular beam epitaxy 348 (1996) 17

Low energy electron diffraction (LEED)

Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the $PrB_6(100)$ and $LaB_6(100)$ surfaces 348 (1996) 133

J. Cerdá, S. Gallego and P.L. de Andres, Fast first-order perturbation approach to the surface structural problem using low energy electron diffraction 348 (1996) 197

Photoelectron diffraction

O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89

Photoelectron holography

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161

Reflection high-energy electron diffraction (RHEED)

T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Y. Horio and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344

Ion scattering spectroscopy

High energy ion scattering (HEIS)

M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75

Low energy ion scattering (LEIS)

C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^7Li^+$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

Molecular beam epitaxy

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped $TiO_2(110)$ surfaces by molecular beam epitaxy 348 (1996) 17

W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Molecule–solid reactions

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Photoelectron spectroscopy

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped $TiO_2(110)$ surfaces by molecular beam epitaxy 348 (1996) 17

H. Idriss, V.S. Lusvardi and M.A. Barteau, Two routes to formaldehyde from formic acid on TiO_2(001) surfaces 348 (1996) 39

Soft X-ray photoelectron spectroscopy (using synchrotron radiation)

J. Nerlov, Q. Ge and P.J. Møller, Resonant photoemission from TiO_2(110) surfaces: implications on surface bonding and hybridization 348 (1996) 28

O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161

Visible and ultraviolet photoelectron spectroscopy

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49

X-ray photoelectron spectroscopy

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1

Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67

J. Nishizawa, Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105

Photon absorption spectroscopy

Infrared absorption spectroscopy

J.A. Glass, Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325

Scanning tunneling microscopy

T. Komeda, Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153

J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

M. Ritter, M. Stindtmann, M. Farle and K. Baberschke, Nanostructuring of the Cu(001) surface by ion bombardment: a STM study 348 (1996) 243

U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261

J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280

N. Kobayashi, K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299

R.A. Goschke, K. Vey, M. Meier, U. Walter, E. Goering, M. Klemm and S. Horn, Tip induced changes of atomic scale images of the vanadiumpentoxide surface 348 (1996) 305

M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Secondary ion mass spectroscopy

J.Kristóf, S. Daolio, C. Piccirillo, B. Facchin and J. Mink, Investigation on the formation of RuO_2 film electrode by secondary ion mass spectrometry 348 (1996) 287

Thermal desorption spectroscopy

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1

R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55

A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

C.J. Jenks, S. Rishi and P.A. Thiel, Effectiveness of a fluorinated nickel surface in catalyzing the decomposition of a perfluoropolyether analog 348 (1996) 175

H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

PHENOMENA

Adsorption kinetics

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

Atom emission

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

Atom–solid interactions

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Catalysis

R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55
Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67

Chemisorption

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1
R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55
Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67
O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89
W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71
U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261
J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280
M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311
J.A. Glass, Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325

Compound formation

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280

Corrosion

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Crystallization

U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261

Diffusion and migration

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185
H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

Electron–solid interactions

N. Doraiswamy and L.D. Marks, Electron beam induced small particle transformations: temperature 348 (1996) L67
J. Cerdá, S. Gallego and P.L. de Andres, Fast first-order perturbation approach to the surface structural problem using low energy electron diffraction 348 (1996) 197

Electron stimulated desorption

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Epitaxy

M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75
N. Ikemiya, K. Yamada and S. Hara, Initial stage of the electrodeposition of Ag on Au(100) observed by in-situ atomic force microscopy 348 (1996) 253
U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261
M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Etching

J.A. Glass, Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325

Faceting

T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Field evaporation

N. Kobayashi, K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299

Growth

J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185
W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227
M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

Ion bombardment

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227
M. Ritter, M. Stindtmann, M. Farle and K. Baberschke, Nanostructuring of the Cu(001) surface by ion bombardment: a STM study 348 (1996) 243

Ion emission

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

Ion–solid interactions

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100
C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^{7}Li^{+}$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

Oxidation

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the PrB_6(100) and LaB_6(100) surfaces 348 (1996) 133
B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71

Photoelectron diffraction

O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89

Physical adsorption

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Sputtering

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

Surface chemical reaction

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1
R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55
A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77
J. Nishizawa, Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105
W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Surface diffusion

W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

Surface electronic phenomena (work function, surface potential, surface states, etc.)

K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168
Y. Horio and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344
C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^{7}Li^{+}$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

Surface energy

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70
K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168

Surface melting

H. Sakai, How does a slab-shaped solid melt? 348 (1996) 387

Surface relaxation and reconstruction

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70
J. Nerlov, Q. Ge and P.J. Møller, Resonant photoemission from TiO_2(110) surfaces: implications on surface bonding and hybridization 348 (1996) 28
K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168
R.A. Goschke, K. Vey, M. Meier, U. Walter, E. Goering, M. Klemm and S. Horn, Tip induced changes of atomic scale images of the vanadiumpentoxide surface 348 (1996) 305

Surface roughening

T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Surface structure, morphology, roughness, and topography

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70
W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115
T. Komeda, Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161
J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185
J. Cerdá, S. Gallego and P.L. de Andres, Fast first-order perturbation approach to the surface structural problem using low energy electron diffraction 348 (1996) 197
M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75
J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280

Surface thermodynamics (including phase transitions)

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70
T. Komeda, Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153
U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261

Surface waves

Phonons

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the $PrB_6(100)$ and $LaB_6(100)$ surfaces 348 (1996) 133

Thermal desorption

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49
A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77
W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Vibrations of adsorbed molecules

B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71

Wetting

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

ELSEVIER

Surface Science 348 (1996) 402–406

surface science

Materials index

ELEMENTAL AND CHEMICAL IDENTITY

Elements

Alkali metals

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168

J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280

N. Kobayashi, K. Hirose and M. Tsukada, First-principles study of Na atom transfer induced by the tip of a STM 348 (1996) 299

C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^7Li^+$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Aluminum

B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71

M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^7Li^+$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

Chlorine

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Copper

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

M. Ritter, M. Stindtmann, M. Farle and K. Baberschke, Nanostructuring of the Cu(001) surface by ion bombardment: a STM study 348 (1996) 243

Germanium

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161

Gold

N. Ikemiya, K. Yamada and S. Hara, Initial stage of the electrodeposition of Ag on Au(100) observed by in-situ atomic force microscopy 348 (1996) 253

J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280

Hydrogen

H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

J.A. Glass, Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325

Lead

J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161

Nickel

O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89

C.J. Jenks, S. Rishi and P.A. Thiel, Effectiveness of a fluorinated nickel surface in catalyzing the decomposition of a perfluoropolyether analog 348 (1996) 175

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

Noble gases

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

Palladium

R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55

Platinum

A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Rhodium

Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67

Ruthenium

H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

Silicon

T. Komeda, Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

J.A. Glass, Jr., E.A. Wovchko and J.T. Yates, Jr., Reaction of atomic hydrogen with hydrogenated porous silicon – detection of precursor to silane formation 348 (1996) 325

T. Suzuki, H. Minoda, Y. Tanishiro and K. Yagi, REM study of high index Si(5 5 12) flat surfaces 348 (1996) 335

Y. Horio and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344

Silver

N. Ikemiya, K. Yamada and S. Hara, Initial stage of the electrodeposition of Ag on Au(100) observed by in-situ atomic force microscopy 348 (1996) 253

Transition metals

H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Compounds (non-molecular solids)

Aluminum oxide

B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71

Borides

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the PrB_6(100) and LaB_6(100) surfaces 348 (1996) 133

Boron nitride

J. Yamauchi, M. Tsukada, S. Watanabe and O. Sugino, Erratum to "First principles study on energetics of cBN(001) reconstructed surfaces" [Surface Science 341 (1995) L1037] 348 (1996) L70

Gallium arsenide

Z. Šroubek and H. Oechsner, Experimental studies of ionization processes in sputtering of GaAs 348 (1996) 100

J. Nishizawa, Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105

Halides

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

C.J. Jenks, S. Rishi and P.A. Thiel, Effectiveness of a fluorinated nickel surface in catalyzing the decomposition of a perfluoropolyether analog 348 (1996) 175

Hydrides

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

Iron pentacarbonyl

H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192

$NaNO_3$

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

Niobium diselenide

J.C. Arnault, J.L. Bubendorff, A. Pimpinelli and J.P. Bucher, Transition in the growth kinetics of vacancy islands on $NbSe_2$ 348 (1996) 185

Organometallics

M.J. Bronikowski and R.J. Hamers, The chemistry of gallium deposition on Si(001) from trimethylgallium: an atomically resolved STM study 348 (1996) 311

Ruthenium dioxide

J.Kristóf, S. Daolio, C. Piccirillo, B. Facchin and J. Mink, Investigation on the formation of RuO_2 film electrode by secondary ion mass spectrometry 348 (1996) 287

Titanium carbide

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49

Titanium oxide

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped TiO_2(110) surfaces by molecular beam epitaxy 348 (1996) 17
J. Nerlov, Q. Ge and P.J. Møller, Resonant photoemission from TiO_2(110) surfaces: implications on surface bonding and hybridization 348 (1996) 28
H. Idriss, V.S. Lusvardi and M.A. Barteau, Two routes to formaldehyde from formic acid on TiO_2(001) surfaces 348 (1996) 39

Vanadium oxide

R.A. Goschke, K. Vey, M. Meier, U. Walter, E. Goering, M. Klemm and S. Horn, Tip induced changes of atomic scale images of the vanadiumpentoxide surface 348 (1996) 305

Molecules

Aldehydes

R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55

Alkenes

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

Aromatics

M. Stichler, P. Zebisch, M. Weinelt and H.-P. Steinrück, Argon desorption as a tool to study the growth of molecular layers 348 (1996) 370

Carbon dioxide

A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77

Carbon monoxide

A. Rar, H. Sugimura, A. Barrera, Y. Ohno and T. Matsushima, Angular and velocity distributions of desorbing product carbon dioxide from different reaction sites on stepped platinum (112) 348 (1996) 77

Epoxides

R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55

Fluorocarbons

C.J. Jenks, S. Rishi and P.A. Thiel, Effectiveness of a fluorinated nickel surface in catalyzing the decomposition of a perfluoropolyether analog 348 (1996) 175

Halogens

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Nitrogen oxides

Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67
K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

Organo-silanes

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1

Oxygen

B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71
W. Wulfhekel, N.N. Lipkin, J. Kliewer, G. Rosenfeld, L.C. Jorritsma, B. Poelsema and G. Comsa, Conventional and manipulated growth of Cu/Cu(111) 348 (1996) 227

Trimethylgallium

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209

Water

K. Knutsen and T.M. Orlando, Low-energy (5–80 eV) electron-stimulated desorption of $H^+(D^+)$, $OH^+(OD^+)$, O^+, and NO^+ from solution-grown $NaNO_3$ crystals 348 (1996) 143

PHYSICAL STATE

Surfaces

Single crystal surfaces

K.E. Tan, M.W. Finnis, A.P. Horsfield and A.P. Sutton, Why TiC(111) is observed to be Ti terminated 348 (1996) 49
J.M. Roesler, T. Miller and T.-C. Chiang, Structure determination of ordered 1/3-monolayer Pb on Ge(111) by photoelectron holography 348 (1996) 161
H.H. Huang, C.S. Seet, C.S. Sreekanth and G.Q. Xu, Migration of H-atoms from metal interface to adsorbed metal carbonyl layers 348 (1996) 192
H. Arce, W.L. Mochán and J.J. Gutiérrez, Minimum energy 2D patterns of atoms adsorbed on a hexagonal lattice 348 (1996) 379

Low index single crystal surfaces

L. Gamble, L.S. Jung and C.T. Campbell, Decomposition and protonation of surface ethoxys on TiO_2(110) 348 (1996) 1
J. Nerlov, Q. Ge and P.J. Møller, Resonant photoemission from TiO_2(110) surfaces: implications on surface bonding and hybridization 348 (1996) 28
R. Shekhar and M.A. Barteau, Ring-opening reactions of ethylene oxide on Pd(110) surfaces 348 (1996) 55
Y. Li and M. Bowker, The adsorption and decomposition of nitrous oxide on Rh(110) and Rh(111) 348 (1996) 67
O. Schaff, V. Fernandez, Ph. Hofmann, K.-M. Schindler, A. Theobald, V. Fritzsche, A.M. Bradshaw, R. Davis and D.P. Woodruff, Coverage-dependent changes in the adsorption geometry of benzene on Ni{111} 348 (1996) 89
W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

N. Yamamoto, E. Rokuta, Y. Hasegawa, T. Nagao, M. Trenary, C. Oshima and S. Otani, Oxygen adsorption sites on the $PrB_6(100)$ and $LaB_6(100)$ surfaces 348 (1996) 133
T. Komeda, Y. Morita and H. Tokumoto, Surface roughening and metastable superstructures on wet-processed Si(111) surface induced by hydrogen desorption 348 (1996) 153
K. Kokko, P.T. Salo, R. Laihia and K. Mansikka, First-principles calculations for work function and surface energy of thin lithium films 348 (1996) 168
A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209
U. Schmidt, S. Vinzelberg and G. Staikov, Pb UPD on Ag(100) and Au(100) – 2D phase formation studied by in situ STM 348 (1996) 261
J.V. Barth, R. Schuster, R.J. Behm and G. Ertl, The system K/Au(111): adsorption and surface restructuring 348 (1996) 280
Y. Horio and A. Ichimiya, Wave fields in Si(111) layers under RHEED conditions 348 (1996) 344
C.B. Weare and J.A. Yarmoff, Resonant neutralization of $^7Li^+$ scattered from alkali/Al(100) as a probe of the local electrostatic potential 348 (1996) 359

Stepped single crystal surfaces

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Surface defects

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Y. Pennec and A. Khater, A method for characterizing the localized dynamics of boundary defects in crystalline systems 348 (1996) L82

Interfaces

Crystalline–amorphous interfaces

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Single crystal epitaxy

Y. Gao, Y. Liang and S.A. Chambers, Synthesis and characterization of Nb-doped $TiO_2(110)$ surfaces by molecular beam epitaxy 348 (1996) 17
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Solid–liquid interfaces

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Adatoms

A.J. Mayne, C.M. Goringe, C.W. Smith and G.A.D. Briggs, Statistical analysis of adsorbates 348 (1996) 209
B.G. Frederick, M.B. Lee and N.V. Richardson, A vibrational characterisation of the O/Al(111) system: a reassignment of HREELS data 348 (1996) L71
M.A. Boshart, A.A. Bailes, III and L.E. Seiberling, A channeled ion energy loss study of the surfactant-mediated growth of Ge on Si(100) 348 (1996) L75
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ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and/or films

Metallic surfaces

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Semiconducting surfaces

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Interfaces

Metal–electrolyte interfaces

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Metal–insulator interfaces

W.K. Walter, D.E. Manolopoulos and R.G. Jones, Chlorine adsorption and diffusion on Cu(111) 348 (1996) 115

Metal–semiconductor interfaces

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Semiconductor–semiconductor interfaces

J. Nishizawa, Y. Oyama, P. Plotka and H. Sakuraba, Optimization of low temperature surface treatment of GaAs crystal 348 (1996) 105

Heterostructures and thin film structures

Semiconductor–semiconductor thin film structures

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